NSN 5961-01-138-9982

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Mounting Method:
Bracket
Semiconductor Material:
Silicon
Power Rating Per Characteristic:
150.00 milliwatts small-signal input power, common-collector of standard range
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0